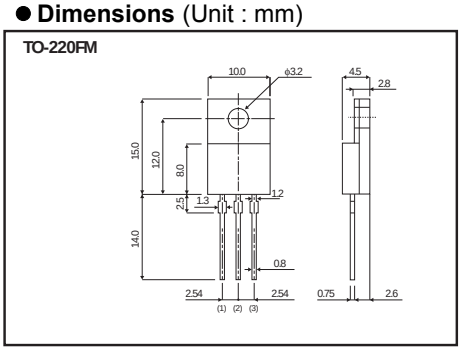
10V Drive Nch MOSFET

RCX450N20

● Structure
Silicon N-channel MOSFET

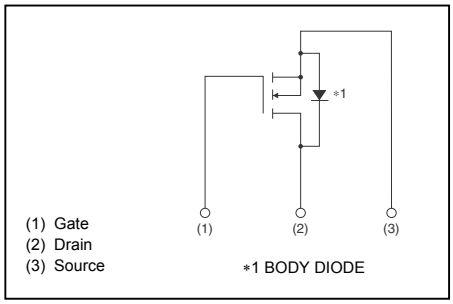
● Dimensions (Unit : mm)



●Features
1) Low on-resistance.
2) High speed switching.
3) Gate-source voltage V_{GSS} garanteed to be ±30V
4) High Power Package (TO-220FM).

● Application
Switching

● Inner circuit



● Packaging specifications

Type	Package	Bulk
	Code	-
	Basic ordering unit (pieces)	500
RCX450N20		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	200	V
Gate-source voltage		V_{GSS}	±30	V
Drain current	Continuous	I_D *3	±45	A
	Pulsed	I_{DP} *1	±180	A
Source current (Body Diode)	Continuous	I_S *3	45	A
	Pulsed	I_{SP} *1	180	A
Avalanche current		I_{AS} *2	22.5	A
Avalanche energy		E_{AS} *2	160	mJ
Power dissipation(Tc=25°C)		P_D	40	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	−55 to +150	°C

*1 Pw≤10μs, Duty cycle≤1%

*2 L≒500μH, V_{DD}=50V, R_G=25Ω, starting Tch=25°C

*3 Limited only by maximum temperature allowed.

● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Case	Rth (ch-c)*	3.12	°C / W

* T_C=25°C

● **Electrical characteristics** (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	±100	nA	V_{GS}=±30V, V_{DS}=0V
Drain-source breakdown voltage	$V_{(BR)DSS}$	200	-	-	V	I_D=1mA, V_{GS}=0V
Zero gate voltage drain current	I_{DSS}	-	-	1	μA	V_{DS}=200V, V_{GS}=0V
Gate threshold voltage	$V_{GS\ (th)}$	3	-	5	V	V_{DS}=10V, I_D=1mA
Static drain-source on-state resistance	$R_{DS\ (on)}$ *	-	42	55	mΩ	I_D=22.5A, V_{GS}=10V
Forward transfer admittance	$\|Y_{fs}\|$ *	17	-	-	S	I_D=22.5A, V_{DS}=10V
Input capacitance	C_{iss}	-	4200	-	pF	V_{DS}=25V
Output capacitance	C_{oss}	-	270	-	pF	V_{GS}=0V
Reverse transfer capacitance	C_{rss}	-	160	-	pF	f=1MHz
Turn-on delay time	$t_{d(on)}$ *	-	52	-	ns	I_D=22.5A, V_{DD}≒100V
Rise time	t_r *	-	210	-	ns	V_{GS}=10V
Turn-off delay time	$t_{d(off)}$ *	-	90	-	ns	R_L=4.4Ω
Fall time	t_f *	-	70	-	ns	R_G=10Ω
Total gate charge	Q_g *	-	80	-	nC	I_D=45A,
Gate-source charge	Q_{gs} *	-	28	-	nC	V_{DD}≒100V
Gate-drain charge	Q_{gd} *	-	28	-	nC	V_{GS}=10V

*Pulsed

●**Body diode characteristics** (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD} *	-	-	1.5	V	I_s=45A, V_{GS}=0V

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics (Ⅰ)

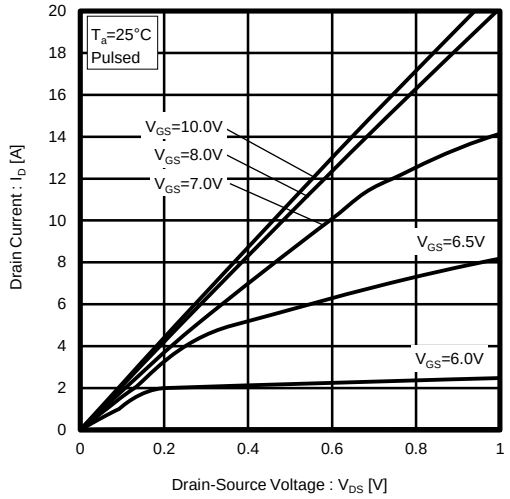


Fig.2 Typical Output Characteristics (Ⅱ)

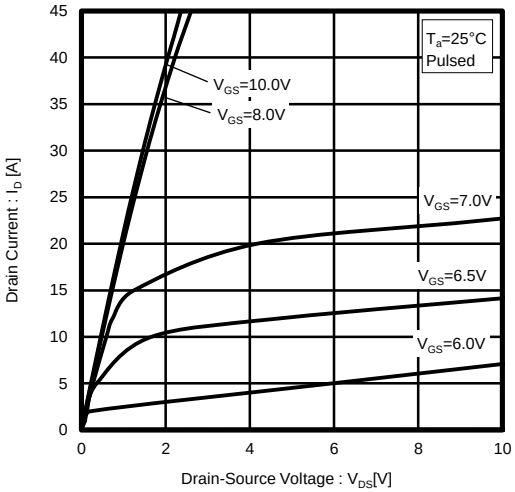


Fig.3 Typical Transfer Characteristics

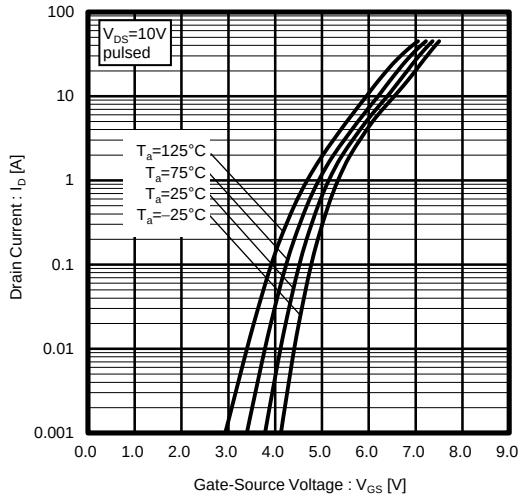


Fig.4 Gate Threshold Voltage vs. Channel Temperature

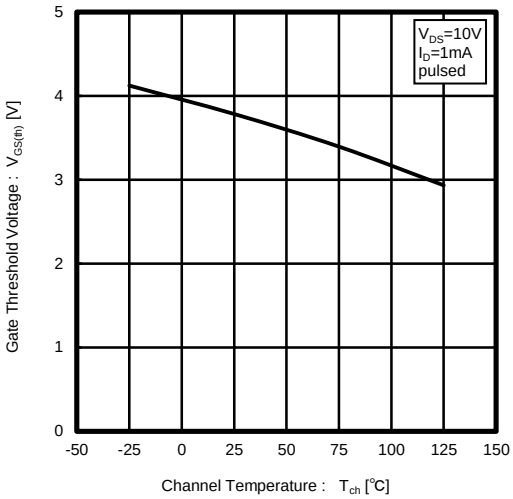


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

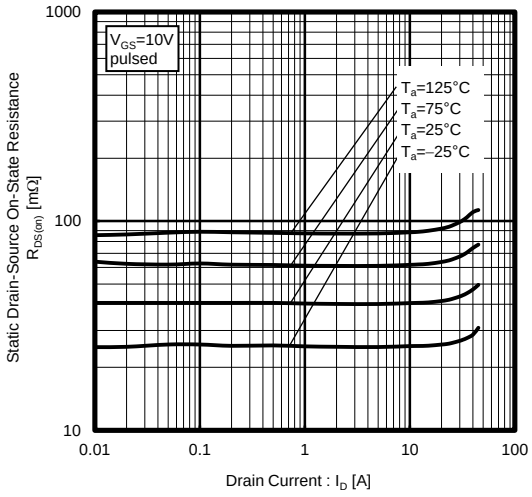


Fig.6 Static Drain-Source On-State Resistance vs. Channel Temperature

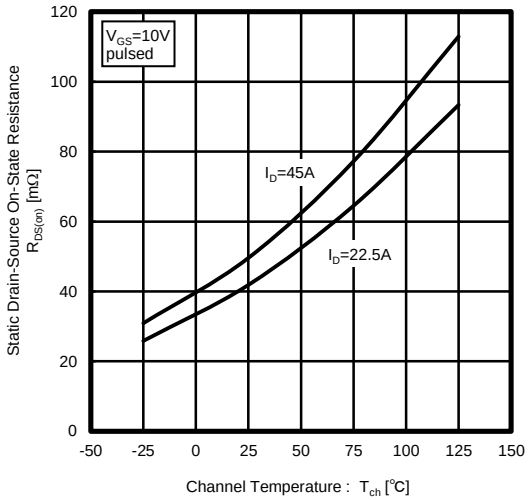


Fig.7 Forward Transfer Admittance vs. Drain Current

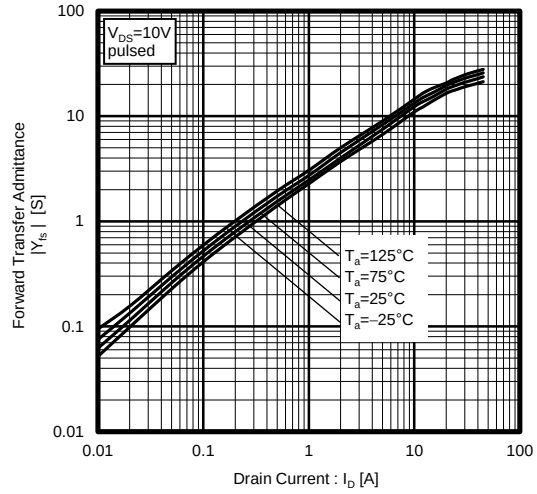


Fig.8 Source Current vs. Source-Drain Voltage

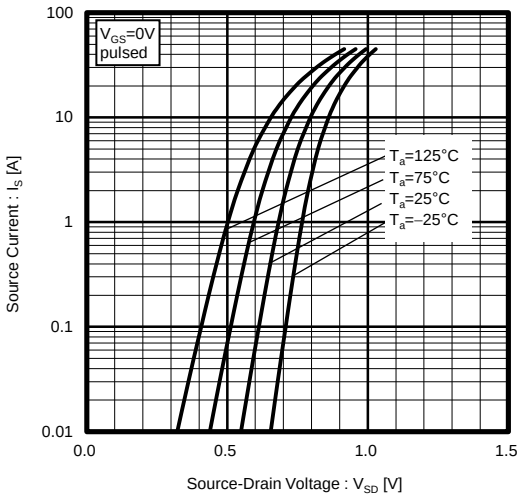


Fig.9 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

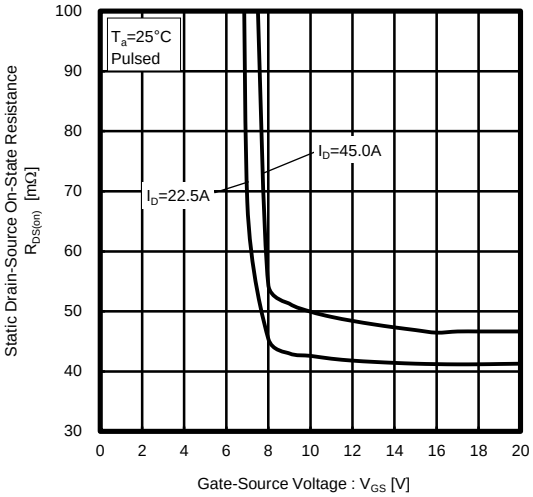


Fig.10 Switching Characteristics

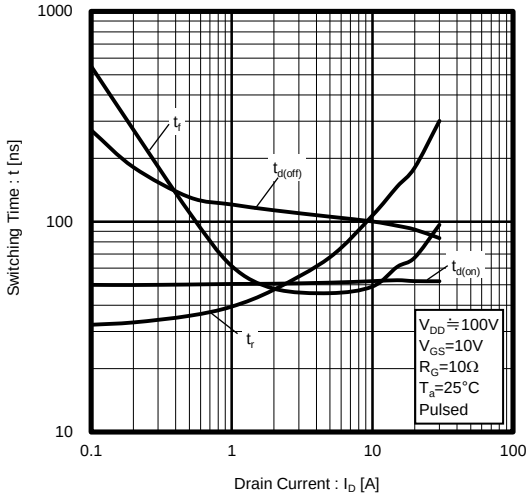


Fig.11 Dynamic Input Characteristics

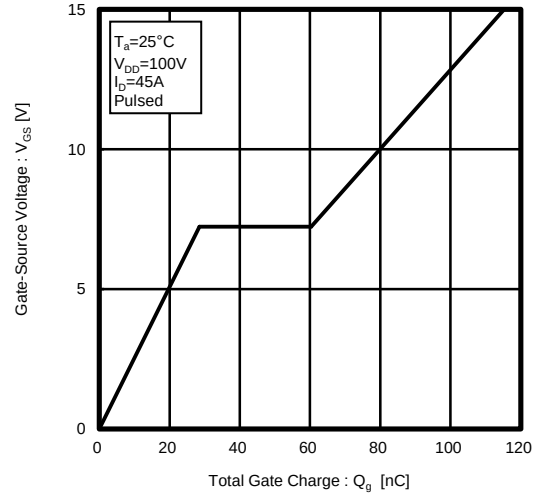


Fig.12 Typical Capacitance vs. Drain-Source Voltage

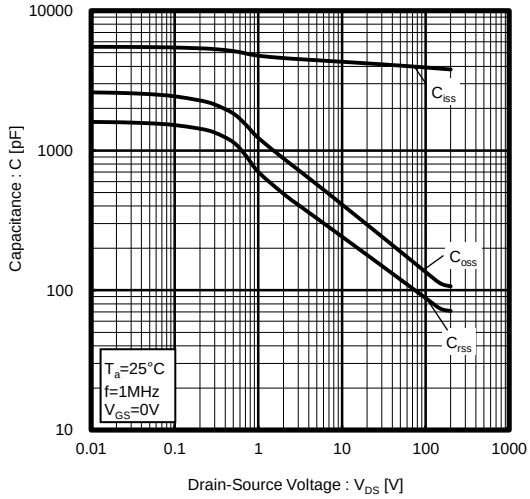


Fig.13 Reverse Recovery Time vs. Source Current

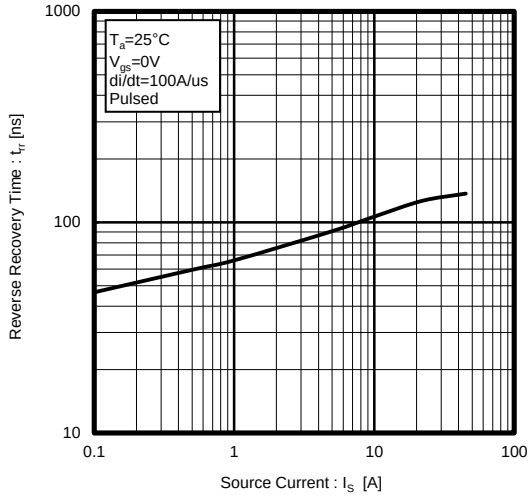


Fig.14 Maximum Safe Operating Area

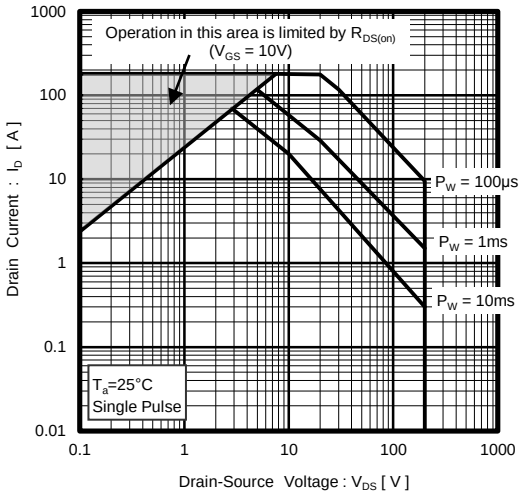
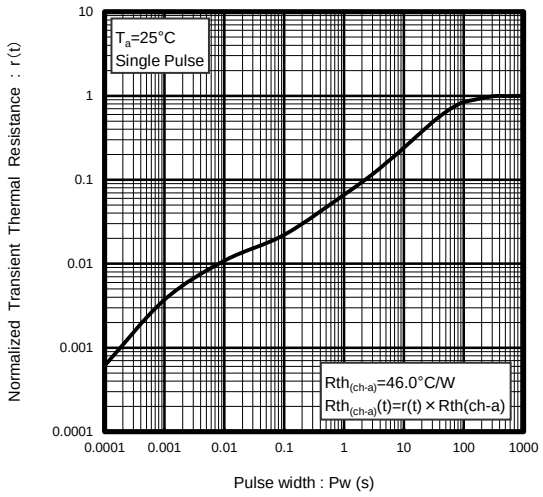


Fig.15 Normalized Transient Thermal Resistance v.s. Pulse Width



● Measurement circuits

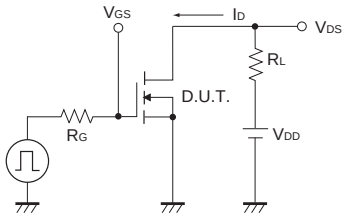


Fig.1-1 Switching Time Measurement Circuit

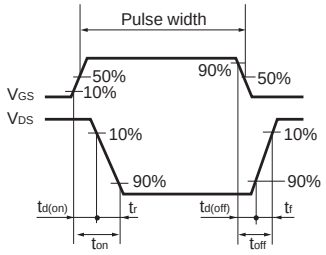


Fig.1-2 Switching Waveforms

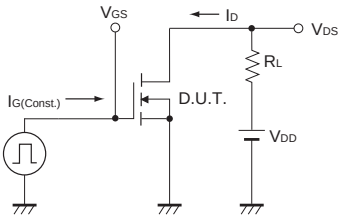


Fig.2-1 Gate Charge Measurement Circuit

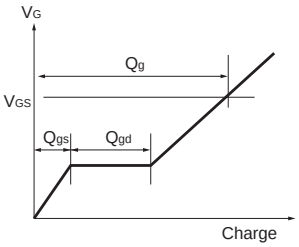


Fig.2-2 Gate Charge Waveform

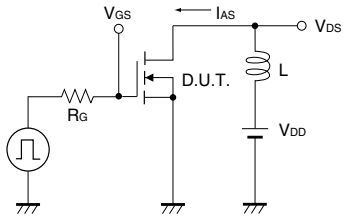


Fig.3-1 Avalanche Measurement Circuit

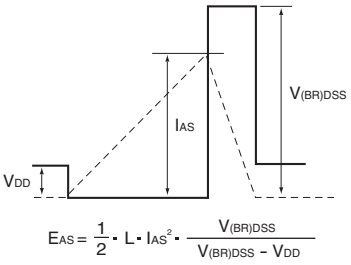


Fig.3-2 Avalanche Waveform

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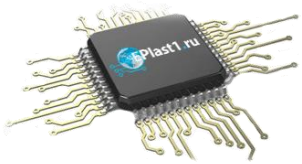
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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